3-Phase BLDC Motor Driver IC

ECN30216S Product Specification　　　　　Rev. 3

1. Product Description

　1.1　Features

　　(1) Maximum Ratings: 600VDC/1.5A, suitable for the system from 200VAC to 240VAC

　　(2) Drives a motor using high voltage PWM (Pulse Width Modulation) control, increasing efficiency

　　(3) Variable speed control by an analog speed command signal (VSP signal)

　　(4) Six IGBTs, six FWDs (Free-Wheeling Diodes), drivers for IGBTs, protection circuits, etc. integrated into a single chip, resulting in space reduction

　　(5) Drives a motor using a high voltage DC power supply and a low voltage DC power supply (15V)

　　(6) A capacitor for top arm power supply is built in, so external capacitor is not required

　1.2　Functions

　　(1) Hall elements applicable (Hall amplifiers are embedded)

　　(2) Power on/off sequence-free (condition: output pin current is less than 1A)

　　(3) FG (Frequency Generator) signal outputs for motor rotational speed monitor (three pulses and one pulse)

　　(4) All IGBT shutoff function

　　(5) Current limit (detects at 0.5V)

　　(6) Over-current protection (detects at 1.0V)

　　(7) Vcc low-voltage detection

　　(8) Over temperature protection (with selection pin to enable/disable)

　　(9) Motor lock protection

　　(10) PWM circuit (enable 20kHz PWM operation)

　　(11) Three-phase distributor circuit

　　(12) Vcc standby function

　　(13) Shutdown function

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1.3 Block Diagram of IC
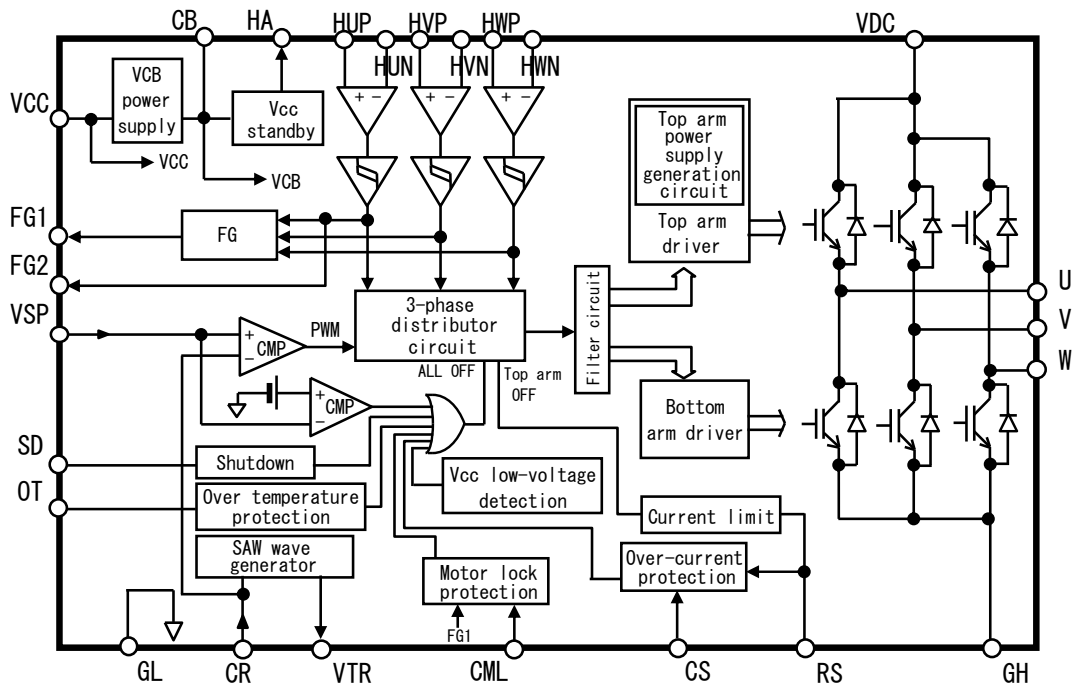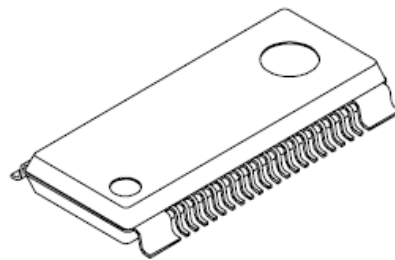
FIGURE 1.3.1 shows block diagram.

FIGURE 1.3.1 Block Diagram of IC

1.4 Package

(Package: HSOP-36N)

FIGURE 1.4.1 Package of ECN30216S

2. Specification

2.1 Maximum Ratings

TABLE 2.1.1 Maximum Ratings   Condition: Ta=25˚C

No.	Item		Symbol	Pin	Rating	Unit	Remarks
1	Output device withstand voltage		VDCM	VDC, U, V, W	600	V	
2	Vcc power supply voltage		VCC	VCC	18	V	
3	Input voltage		VIN	VSP, RS, HUP, HUN, HVP, HVN, HWP, HWN, SD, OT	−0.5 to VCB+0.5	V	
4	Output current	Pulse	IP	U, V, W	1.5	A	Note 1
5		DC	IDC		0.7		
6	VCB supply output current		ICBMAX	CB, HA	50	mA	Note 2
7	Junction operating temperature		Tjop	—	−40 to +135	˚C	Note 3
8	Junction temperature		Tj	—	+150	˚C	
9	Storage temperature		Tstg	—	−40 to +150	˚C	

Note 1: Output IGBTs can handle this peak current.
Note 2: "ICBMAX" represents the sum of output currents at the CB pin and the HA pin.
Note 3: Thermal resistance
      Between junction and case: Rjc = 3˚C/W (Reference value)

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2.2 Electrical Characteristics

TABLE 2.2.1 Electrical Characteristics (1/2)　　　　Suffix (T: Top arm, B: Bottom arm)　　　Condition: Ta=25°C

No.	Item		Symbol	Pin	Min.	Typ.	Max.	Unit	Condition
1	Standby current		IDCH	VDC	−	0	0.1	mA	VSP=0V, VDC=325V, VCC=15V
2			ICC	VCC	−	4	10	mA	VSP=0V, VCC=15V, ICB=0A　Note 7
3	IGBT collector-emitter		VONT	U, V, W	−	2.0	3.0	V	I=0.35A, VCC=15V
4	saturation voltage		VONB		−	2.0	3.0	V	
5	Free-wheeling diode		VFDT		−	1.6	2.8	V	I=0.35A
6	forward voltage		VFDB		−	1.6	2.8	V	
7	VTR output resistance		RVTR	VTR	−	200	400	Ω	IVTR=±1mA, VCC=15V
8	SAW wave	High/Low level	VSAWH	CR	4.9	5.4	5.9	V	VCC=15V
9			VSAWL		1.7	2.1	2.4	V	
10		Amplitude	VSAWW		2.8	3.3	3.8	V	VCC=15V　　Note 1
11	Current limit	Reference voltage	Vref1	RS	0.45	0.50	0.55	V	VCC=15V
12		Delay time	Tref1		1.2	2.0	4.5	µs	
13	Over-current protection	Reference voltage	Vref2	RS,CS	0.8	1.0	1.2	V	VCC=15V
14		Delay time	Tref2		−	1.7	2.7	µs	VCC=15V, CF=470pF, RF=2MΩ
15		Recovery time	Trs		−	1.0	2.0	ms	
16	RS input current		IILRS	RS	−100	−	−	µA	VCC=15V, RS=0V Note 5
17	Hall signal input	Minimum differential voltage	VHOS	HUP, HUN, HVP, HVN, HWP, HWN	60	−	−	mVp-p	VCC=15V Note 2
18		Current	IH		−	−	2	µA	
19		Common mode voltage range	VHCM		3	−	6	V	
20		Hysteresis	VHHYS		20	40	60	mV	
21		Voltage L→H	VHLH		−5	20	45	mV	
22		Voltage H→L	VHHL		−45	−20	5	mV	
23	VSP input	Current	IVSPH	VSP	5	−	100	µA	VSP=5.0V, VCC=15V Pull-down resistor Note 3
24		Offset voltage	SPCOMOF		−40	60	160	mV	VCC=15V Voltage from CR pin
25		All off operating voltage	Voff		0.85	1.23	1.60	V	VCC=15V
26	VCB supply output	Voltage	VCB	CB	6.8	7.5	8.2	V	VCC=15V, ICB=0A Note 7
27		Current	ICB		−	−	45	mA	VCC=15V　　Note 7
28	HA output resistance		RHA	HA	−	20	40	Ω	VCC=15V, IHA=10mA
29	FG1, FG2 output resistance		RFGP	FG1, FG2	−	0.9	3.0	kΩ	IFG=1mA, VCC=15V Note 4
30			RFGN		−	0.4	1.5	kΩ	IFG=−1mA, VCC=15V Note 4
31	Vcc low-voltage detection	Operating voltage	LVSDON	VCC, U, V, W	11.0	12.0	12.9	V	
32		Recovery voltage	LVSDOFF		11.1	12.5	13.0	V	
33	Minimum pulse width (top arms)		TMINT	U, V, W	0.8	−	−	µs	VCC=15V　　Note 6

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TABLE 2.2.1 Electrical Characteristics (2/2)   Suffix (T: Top arm, B: Bottom arm)   Condition: Ta=25˚C

No.	Item		Symbol	Pin	Min.	Typ.	Max.	Unit	Condition
34	Maximum PWM ON duty		DMAX	VSP	92	95	98	%	VCC=15V, fPWM=20kHz
35	Over temperature protection	Operating temperature	TSDON	U, V, W	140	170	195	˚C	VCC=15V
36		Recovery temperature	TSDOFF		115	145	170	˚C	
37	Selection pin to enable/ disable over temperature protection	Input voltage	VIHOT	OT	6.0	—	—	V	VCC=15V Note 8
38			VILOT		—	—	1.0	V	
39		Input current	IIHOT		—	—	100	µA	VCC=15V, OT=5V
40	Motor lock protection	Operating time	TMLON	CML	0.6	2.0	3.0	ms	VCC=15V, CM=1000pF
41		Recovery time	TMLOFF		5	12	20	ms	
42	Shutdown function	Operating voltage	Vref3	SD	1.15	1.23	1.31	V	VCC=15V
43		Recovery voltage	Vref4		1.10	1.18	1.26	V	
44		Delay time	Tref3		—	2.5	5.0	µs	
45	SD pin input current		IIHSD		—	—	2	µA	VCC=15V, SD=5V Note 9
46			IILSD		−2	—	—	µA	VCC=15V, SD=0V Note 9

Note 1: The amplitude of SAW wave (i.e., VSAWW) is determined by the following equation.

   VSAWW = VSAWH − VSAWL (V)

Note 2: The equivalent circuit is shown in FIGURE 2.2.1.
Note 3: Internal pull-down resistor is typically 240kΩ. The equivalent circuit is shown in FIGURE 2.2.2.
Note 4: The equivalent circuit is shown in FIGURE 2.2.3.
Note 5: Internal pull-up resistor is typically 200kΩ. The equivalent circuit is shown in FIGURE 2.2.4.
Note 6: The minimum pulse width to pass the filter circuit.
Note 7: "ICB" represents the sum of output currents at the CB pin and the HA pin.
Note 8: Internal pull-down resistor is typically 200kΩ. The equivalent circuit is shown in FIGURE 2.2.5.
Note 9: The equivalent circuit is shown in FIGURE 2.2.6.
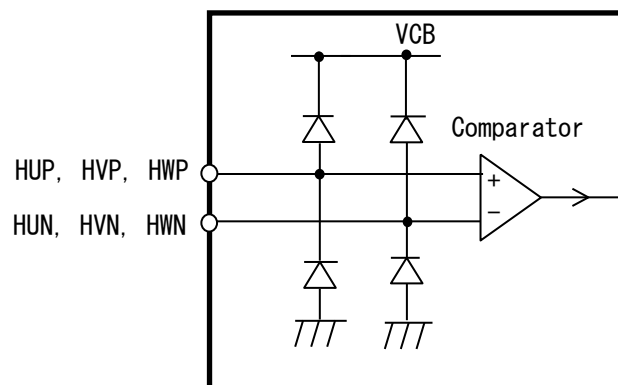
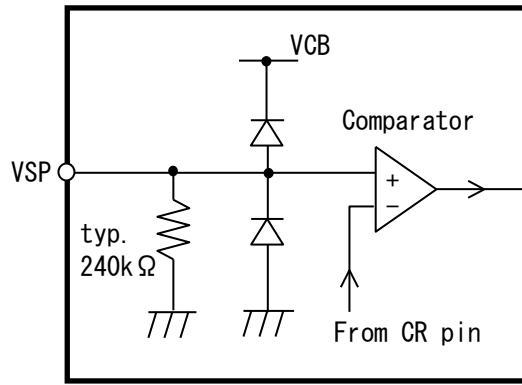**FIGURE 2.2.1   Equivalent Circuit Around Hall Signal Pins**

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FIGURE 2.2.2　Equivalent Circuit Around VSP Pin
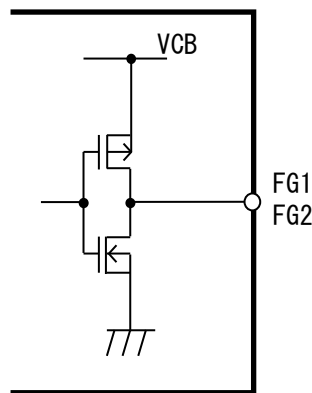
FIGURE 2.2.3　Equivalent Circuit Around FG1, FG2 Pins
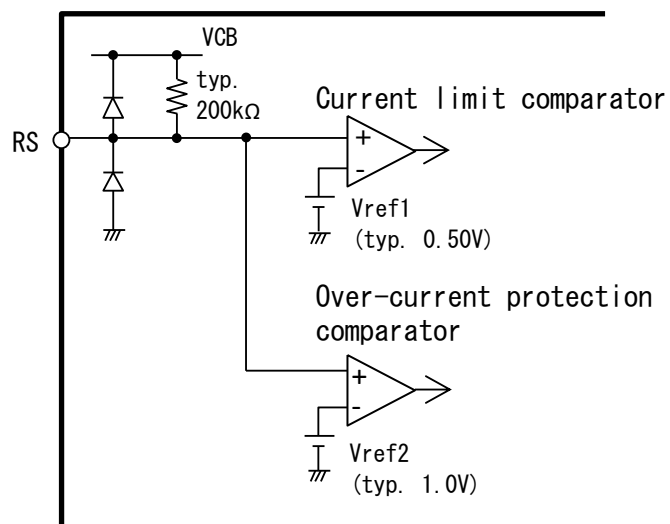
FIGURE 2.2.4　Equivalent Circuit Around RS Pin
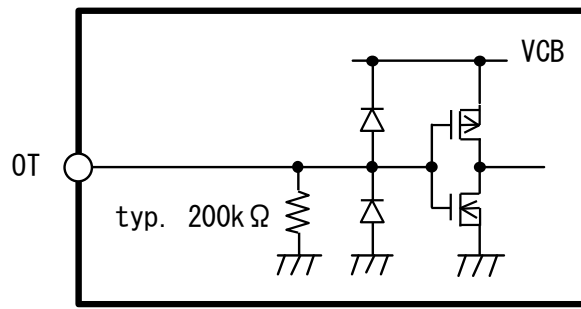
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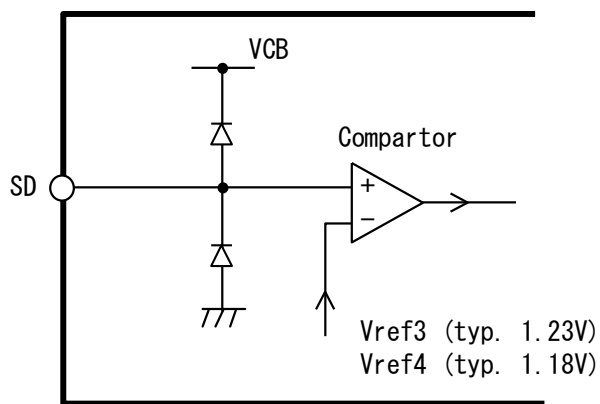**FIGURE 2.2.5 Equivalent Circuit Around OT Pin**

FIGURE 2.2.6 Equivalent Circuit Around SD Pin

2.3 Operating Condition

TABLE 2.3.1 Operating Condition

No.	Item	Symbol	Pin	Min.	Typ.	Max.	Unit
1	Supply voltage	VDCop	VDC	100	325	450	V
2		VCCop	VCC	13.5	15.0	16.5	V

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2.4 Functions and Operations
2.4.1 Truth Table
TABLE 2.4.1.1 Truth Table

Mode	Hall signal input			U-phase		V-phase		W-phase		FG1 output	FG2 output
	HU	HV	HW	Top arm	Bottom arm	Top arm	Bottom arm	Top arm	Bottom arm		
(1)	H	L	H	OFF	ON	ON	OFF	OFF	OFF	H	H
(2)	H	L	L	OFF	ON	OFF	OFF	ON	OFF	L	H
(3)	H	H	L	OFF	OFF	OFF	ON	ON	OFF	H	H
(4)	L	H	L	ON	OFF	OFF	ON	OFF	OFF	L	L
(5)	L	H	H	ON	OFF	OFF	OFF	OFF	ON	H	L
(6)	L	L	H	OFF	OFF	ON	OFF	OFF	ON	L	L
—	L	L	L	OFF	OFF	OFF	OFF	OFF	OFF	L	L
—	H	H	H	OFF	OFF	OFF	OFF	OFF	OFF	H	H

Note: Inputs H: Input voltage between： H∗P and H∗N＞VHLH
Inputs L: Input voltage between： H∗P and H∗N＜VHHL

2.4.2 Timing Chart
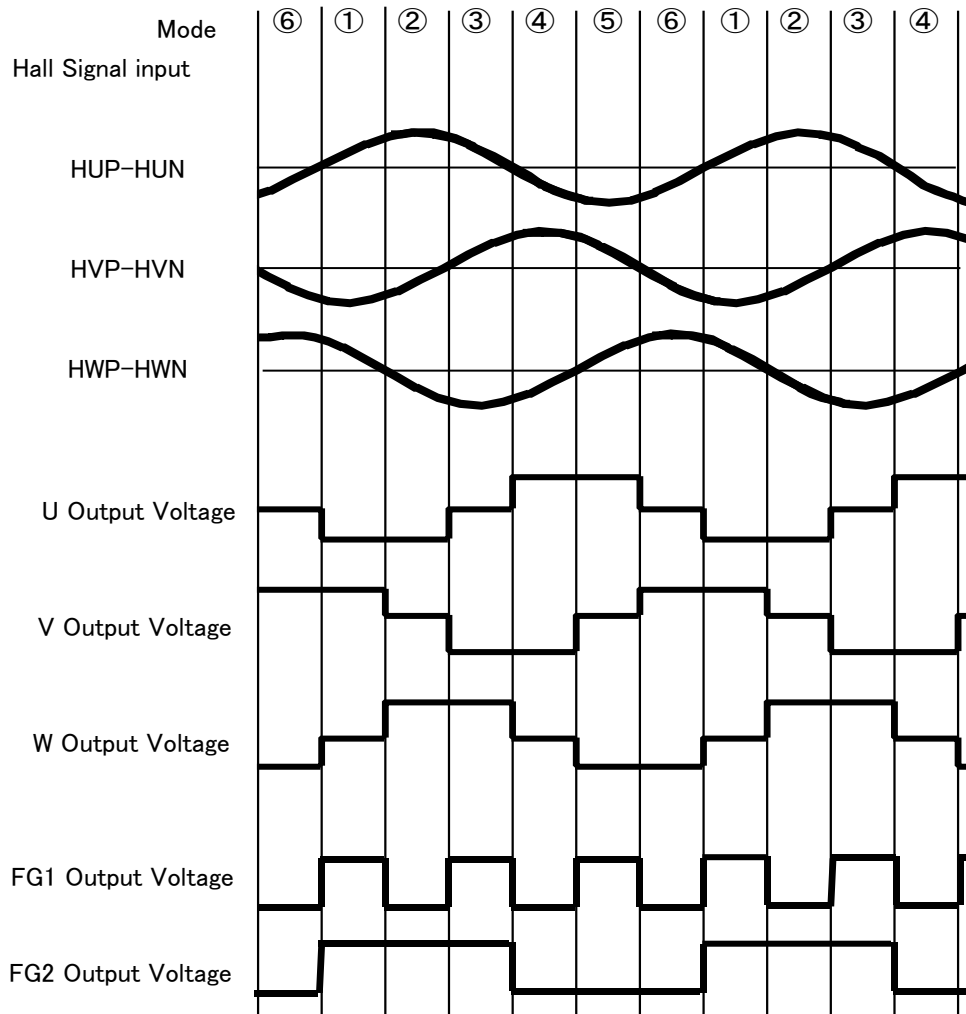
FIGURE 2.4.2.1 Timing Chart

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2.4.3 PWM Operation
The PWM signal is generated by comparing the input voltage at the VSP pin with an internal SAW wave voltage (available at the CR pin). The relation between VSP input voltage and PWM duty is shown in FIGURE 2.4.3.1. The PWM duty represents the duty of IGBT gate drive signals.
The voltages at output pins (U, V, W) may be different from the figure depending on conditions. The PWM is operated by top arms.
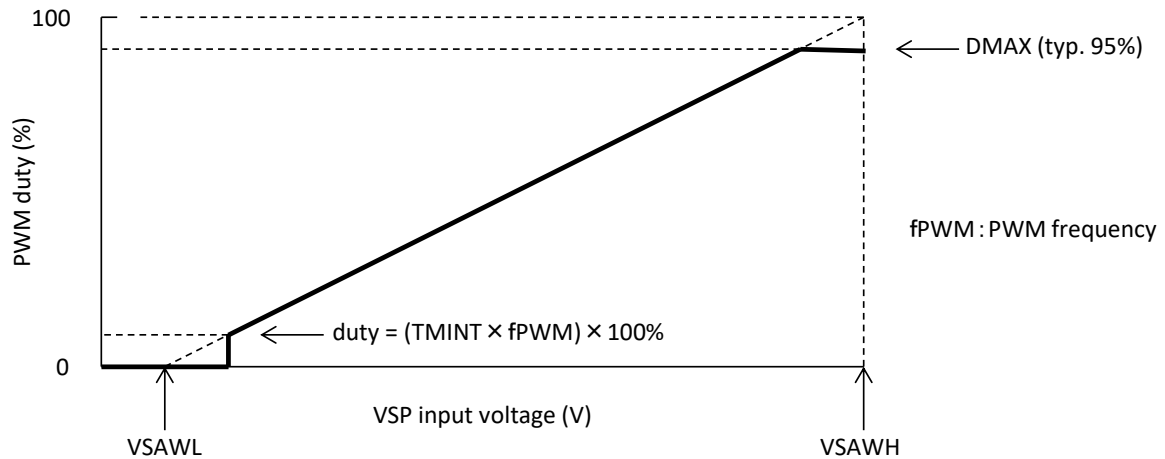

Plot description text inside figure:
- DMAX (typ. 95%)
- fPWM : PWM frequency
- duty = (TMINT × fPWM) × 100%
- VSP input voltage (V)
- PWM duty (%)
- VSAWL
- VSAWH

FIGURE 2.4.3.1 Relation between VSP Input Voltage and PWM Duty

2.4.4 Current Limit
This IC detects current using an external shunt resistor Rs. When the voltage at the shunt resistor Rs reaches the current limit reference voltage (Vref1, typ. 0.50V), all top arm IGBTs are turned off. This off state is automatically reset once per internal CLOCK period (available at VTR pin).

2.4.5 Over-current Protection
When the voltage at the shunt resistor Rs reaches the over-current protection reference voltage (Vref2, typ. 1.0V), all IGBTs (top and bottom arms) are turned off. When the over-current protection recovery time (Trs, typ. 1.0ms) passes, the IC returns to a state in which the IGBTs operate depending on input signals. When this function is not used, connect the CS pin to the CB pin.
When the IGBTs of the top and bottom arms are all turned off by operation of this protection or other function during motor driving, the power supply voltage may rise as a result of a regenerative current flow. The power supply voltage must not exceed the maximum rating (600V).

2.4.6 Vcc Low-voltage Detection
When Vcc voltage drops below the operating voltage of the Vcc low-voltage detection (LVSDON, typ. 12.0V), all IGBTs (top and bottom arms) are turned off. When Vcc voltage goes up above the recovery voltage of the Vcc low-voltage detection (LVSDOFF, typ. 12.5V), the IC returns to a state in which the IGBTs operate depending on input signals.

2.4.7 All IGBT Shutoff Function
When the input voltage at the VSP pin drops below VSAWL (typ. 2.1V), the IC stops the motor drive. When the input voltage at the VSP pin drops further from VSAWL and becomes below Voff (typ. 1.23V), the IGBTs (top and bottom arms) are all shut off to reduce current consumption within the IC. The state of the output IGBTs with regard to the VSP input voltage is shown in TABLE 2.4.7.1.

TABLE 2.4.7.1 IGBT Operation to VSP Input Voltage

VSP Input Voltage	Motor drive state	Top Arm IGBTs	Bottom Arm IGBTs
0V≦VSP＜Voff	Stop	All OFF	All OFF
Voff≦VSP＜VSAWL	Stop	All OFF	Based on TABLE 2.4.1.1
VSAWL≦VSP	Drive	Based on TABLE 2.4.1.1	Based on TABLE 2.4.1.1

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2.4.8 Motor Lock Protection

If a motor is locked, the FG1 signal is fixed at "H" or "L". When the operating time (t1) passes in this state, the motor lock state is detected. Then all IGBTs (top and bottom arms) are turned off. After that, when the recovery time (t2) passes, the IC returns to a state in which the IGBTs operate depending on input signals.

The operating time and recovery time are adjustable by the capacitance of the external capacitor CM.

Operating time: $t1(s) = \{TMLON(ms)/1000\} \times \{CM(pF)/1000(pF)\}$

Recovery time: $t2(s) = \{TMLOFF(ms)/1000\} \times \{CM(pF)/1000(pF)\}$

If the motor takes some time to start up because of low Vdc voltage or high-load, and so on, the motor lock state may be detected during motor start-up. Set the capacitance of the external capacitor CM considering star-up time variation.

The motor lock state is not detected under any of the following conditions (1) to (4).

(1) VSP input voltage $\leqq$ typ. 2.2V

(2) Vcc low-voltage detection operates.

(3) Over temperature protection operates.

(4) Shutdown function operates.

When the motor lock protection is not used, connect the CML pin to the GL pin.

2.4.9 Over Temperature Protection

When IC temperature exceeds the operating temperature of over temperature protection (TSDON, typ. 170°C), all IGBTs (top and bottom arms) are turned off. When IC temperature goes below the recovery temperature of over temperature protection (TSDOFF, typ. 145°C), the IC returns to a state in which the IGBTs operate depending on input signals.

2.4.10 Selection Pin to Enable/disable Over Temperature Protection

When using the over temperature protection, connect the OT pin to the GL pin. When the over temperature protection is not used, connect the OT pin to the CB pin.

2.4.11 Vcc Standby Function

When the input voltage at the VSP pin is more than the all off operating voltage (Voff, typ.1.23V), the current is applied from the HA pin to the Hall elements.

When the input voltage at the VSP pin is less than the all off operating voltage, the current to the Hall elements is shut off to reduce standby power consumption from Vcc power supply.

When the current to the Hall elements is shut off, the voltages at the Hall signal input pins (H∗P, H∗N) are fixed at "L". At this time, the FG1 and the FG2 output "L". If there is a need to confirm the motor rotating state through the FG1 or the FG2 output signal while the VSP input voltage is below the all off operating voltage, do not use this function (the HA pin). Use the CB pin as the power supply for the Hall elements. When this function is not used, open the HA pin or connect it to the CB pin.
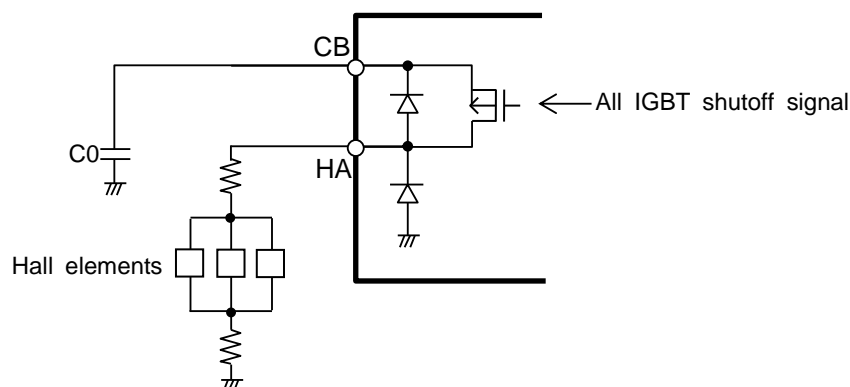
FIGURE 2.4.11.1 Usage Example of Hall Elements and Internal Equivalent Circuit

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2.4.12 Shutdown Function
When the voltage at the SD pin reaches the shutdown operating voltage (Vref3, typ. 1.23V), all IGBTs (top and bottom arms) are turned off. After that, when the voltage at the SD pin falls below the shutdown recovery voltage (Vref4, typ. 1.18V), the IC returns to a state in which the IGBTs operate depending on input signals.

This function can be used as an over-voltage protection when over-voltage is applied on the VDC pin. The operating voltage and recovery voltage of the over-voltage protection are adjustable by the resistance values of external resistors ROVP1 and ROVP2 which are connected between the VDC pin and GL pin. These voltages can be calculated using the following equations:

Over-voltage protection operating voltage：$OVPON(V) = (ROVP1(\Omega)+ROVP2(\Omega))/ROVP2(\Omega) \times Vref3(V)$

Over-voltage protection recovery voltage：$OVPOFF(V) = (ROVP1(\Omega)+ROVP2(\Omega))/ROVP2(\Omega) \times Vref4(V)$

When this function is not used, connect the SD pin to the GL pin.

2.4.13 Power On/Off Sequence-free
When the current at the output pins is below 1A, IGBT current saturation does not occur regardless of power on/off sequence of the Vcc power supply, Vdc power supply and VSP input voltage.
However, be aware that when the Vdc power supply is powered on after the Vcc power supply and VSP input voltage power on with the motor lock protection enabled, the motor may take some time to start up because the motor lock protection operates.

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3. Standard Applications

3.1 External Components

TABLE 3.1.1 External Components

Component	Standard value	Usage	Remarks
C0	1.0μF±10%, 25V	Smooths the internal power supply (VCB)	
CV1	1.0μF±10%, 25V	Smooths the Vcc power supply	Note 1
CV2	33nF±10%, 630V	Smooths the Vdc power supply	Note 2
DZ	5W	Absorbs Vdc line surge voltage	
C1, C2, C3	1000pF±10%, 25V	Eliminates Hall signal noise	Note 3
Rs	1Ω±1%, 1W	Sets current limit	Note 4
CTR	2200pF±5%, 25V	Sets PWM frequency	Note 5
RTR	11kΩ±5%		
CM	1.0μF±10%, 25V	For motor lock protection	
CF	470pF±10%, 25V	For over-current protection	
RF	2MΩ±10%		
COVP	0.1μF±10%, 25V	For over-voltage protection	Note 6
ROVP1	–		Note 7
ROVP2	–		

Note 1: As necessary, increase the capacitance and add a zener diode in consideration of noise immunity.

Note 2: As necessary, increase the capacitance in consideration of noise immunity.

Note 3: Optimize the capacitance corresponding to conditions.

Note 4: The current limit set value can be calculated as follows.

$$I = Vref1 / Rs \ (A)$$

To determine the shunt resistor Rs, see TABLE 3.1.1 and Section 4.

Note 5: The PWM frequency is approximated by the following equation.

$$fPWM \fallingdotseq 0.494 / (CTR \times RTR) \ (Hz) \quad (fPWM \geqq 16kHz \ recommended)$$

Note 6: If the influence of noise is large, adjust the capacitance of the capacitor COVP as necessary.

Note 7: See Section 2.4.12 to determine the over-voltage protection resistors ROVP1 and ROVP2.
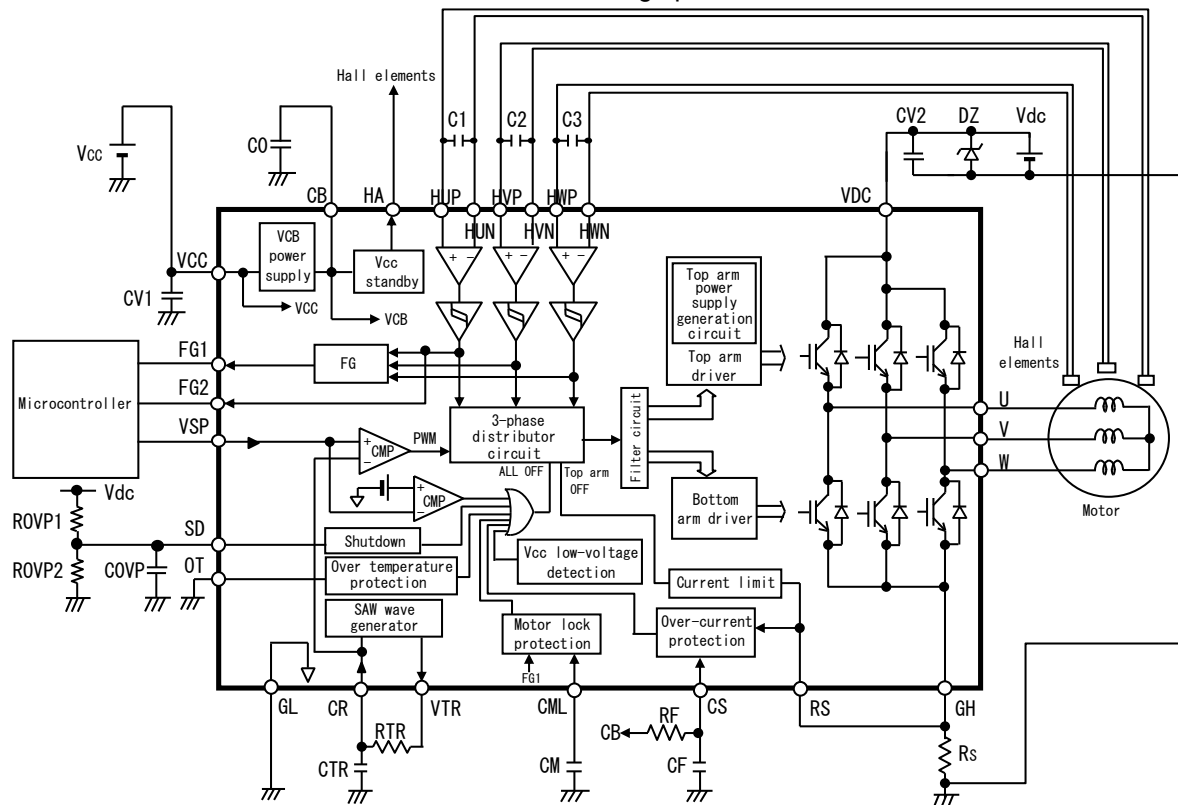
FIGURE 3.1.1 Block Diagram and External Components of IC

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4. Safe Operation Area (SOA) and Derating

4.1 Safe Operation Area (SOA)
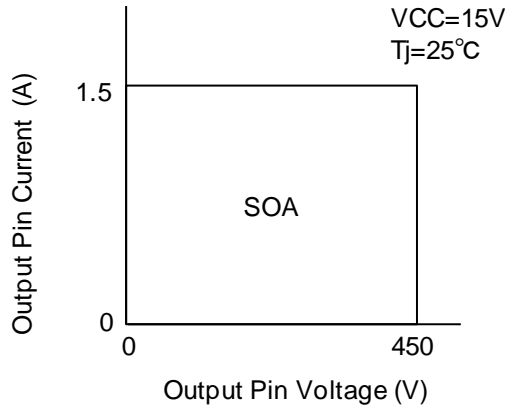The current and voltage at output pins must not be outside the SOA shown in FIGURE 4.1.1.

FIGURE 4.1.1 SOA

4.2 Power On/Off Sequence and Current Derating for VCC Pin Voltage
The current derating for VCC pin voltage is shown in FIGURE 4.2.1. Use the output pin current below the derating curve. When the output pin current is less than 1A, power on/off sequence is free.
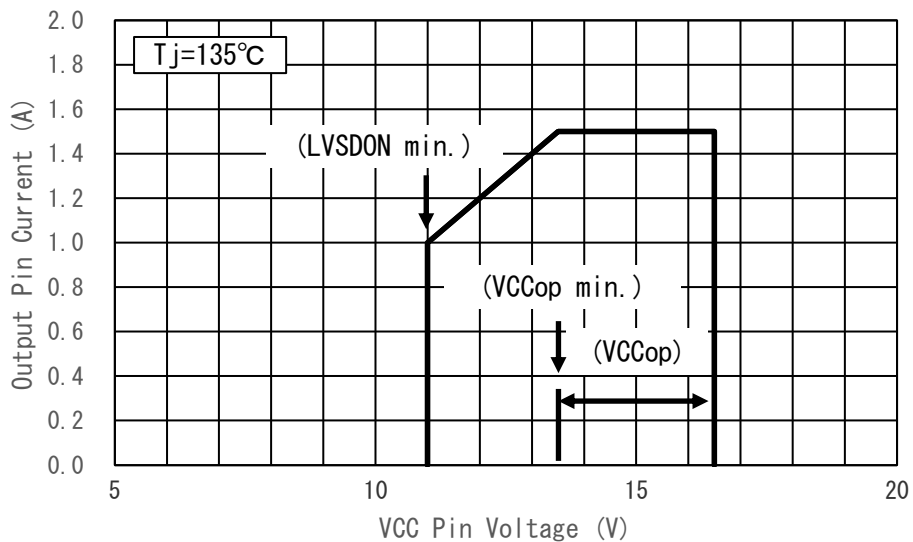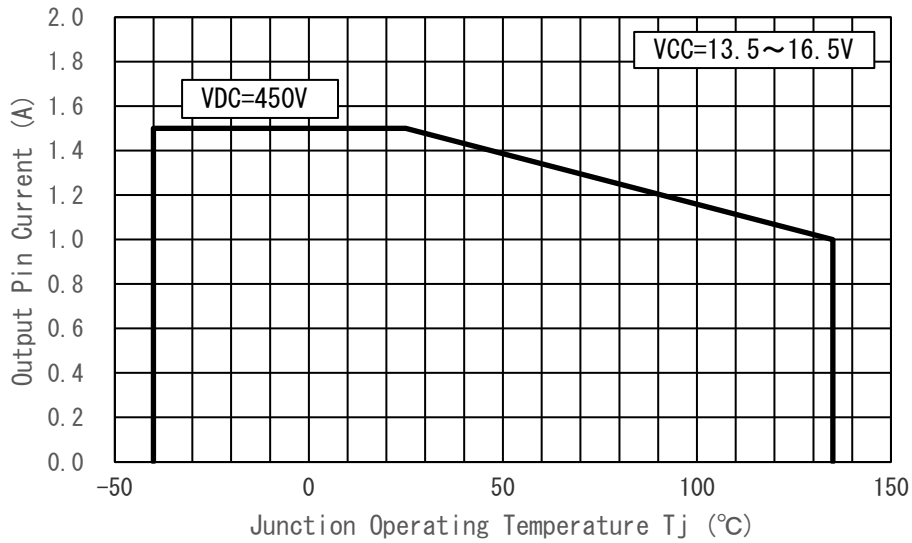

FIGURE 4.2.1 Current Derating for VCC Pin Voltage

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4.3 Current Derating for Junction Operating Temperature
The current derating for junction operating temperature is shown in FIGURE 4.3.1. Use the output pin current below the derating curve.

FIGURE 4.3.1 Current Derating for Junction Operating Temperature

4.4 Shunt Resistor Setting
When setting the current limit, consider the variability of the reference voltage (Vref1), the variability of shunt resistor (Rs) and the delay time.
The current must be below the derating curves of FIGURE 4.2.1 and FIGURE 4.3.1.

4.5 General Design Derating Standards
(a) Temperature - Junction operating temperature must be kept under 110°C.

Junction operating temperature depends on various parameters such as power supply voltages, ambient temperature, load, heat dissipation routes. Test it sufficiently by using actual systems.

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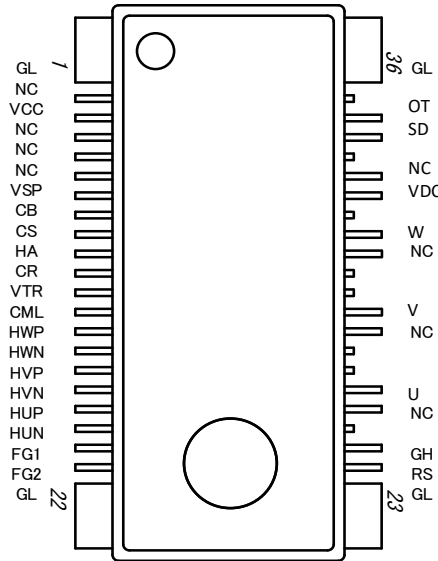
5. Pin Locations

FIGURE 5.1 Pin Locations (Top view)

6. Pin Assignments
TABLE 6.1 Pin Assignments

Pin No.	Symbol	Pin functions	Remarks
1, 22, 23, 36	GL	Ground	
2, 4, 5, 6, 26, 28, 30, 33	NC	No connection	Note 2
3	VCC	Control power supply	
7	VSP	Analog speed command signal input	
8	CB	VCB power supply output	
9	CS	For over-current protection	
10	HA	Output for Vcc standby function	
11	CR	Connect a resistor and a capacitor to set the PWM frequency	
12	VTR	Connect a resistor to set the PWM frequency	
13	CML	For motor lock protection	
14	HWP	W-phase Hall signal plus input	
15	HWN	W-phase Hall signal minus input	
16	HVP	V-phase Hall signal plus input	
17	HVN	V-phase Hall signal minus input	
18	HUP	U-phase Hall signal plus input	
19	HUN	U-phase Hall signal minus input	
20	FG1	Output for motor rotational speed monitor (three pulses)	
21	FG2	Output for motor rotational speed monitor (one pulse)	
24	RS	Input for current limit and over-current protection	
25	GH	Emitters of bottom arm IGBTs and anodes of bottom arm FWDs (Connected to a shunt resistor)	
27	U	U-phase output	Note 1
29	V	V-phase output	Note 1
31	W	W-phase output	Note 1
32	VDC	High voltage power supply	Note 1
34	SD	For shutdown function	
35	OT	Selection to enable/disable over temperature protection	

Note 1: High voltage pin.
Note 2: Not connected to the chip in the IC.

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7. Inspection

Hundred percent inspection shall be conducted on electric characteristics at room temperature. For the operating temperature and recovery temperature of the over temperature protection and the input voltage of the selection pin to enable/disable over temperature protection, equivalent inspections are conducted at room temperature.

8. Precautions for Use

8.1 Countermeasures against Electrostatic Discharge (ESD)

(a) Customers need to take precautions to protect ICs from electrostatic discharge (ESD). The material of the container or any other device used to carry ICs should be free from ESD, which can be caused by vibration during transportation. Use of electrically conductive containers is recommended as an effective countermeasure.

(b) Everything that touches ICs, such as the work platform, machine, measuring equipment, and test equipment, should be grounded.

(c) Workers should be high-impedance grounded ($100k\Omega$ to $1M\Omega$) while working with ICs, to avoid damaging the ICs by ESD.

(d) Friction with other materials, such as high polymers, should be avoided.

(e) When carrying a PCB with a mounted IC, ensure that the electric potential is maintained at a constant level using the short-circuit terminals and that there is no vibration or friction.

(f) The humidity at an assembly line where ICs are mounted on circuit boards should be kept around 45 to 75 percent using humidifiers or such. If the humidity cannot be controlled effectively, using ionized air blowers (ionizers) is effective.

8.2 Output Short-circuit Protection

Our IC could break by a short circuit (ex. load short). Therefore, external protection is needed.

8.3 Maximum Ratings

Regardless of changes in external conditions during use of our IC, the "maximum ratings" described in this document should never be exceeded when designing electronic circuits that employ our IC. If maximum ratings are exceeded, our IC may be damaged or destroyed. In no event shall our company be liable for any failure in our IC or any secondary damage resulting from use at a value exceeding the maximum ratings.

8.4 Derating Design

Continuous high-load operation (high temperatures, high voltages, large currents) should be avoided and derating design should be applied, even within the ranges of the maximum ratings, to ensure reliability.

8.5 Safe Design

Our IC may fail due to accidents or unexpected surge voltages. Accordingly, adopt safe design features, such as redundancy and measures to prevent misuse, in order to avoid extensive damage in the event of a failure.

8.6 Application

If our IC is applied to the following uses where high reliability is required, obtain the document of permission from our company in advance.
・Automobile, Train, Vessel, etc.
Do not apply our IC to the following uses where extremely high reliability is required.
・Nuclear power control system, Aerospace instrument, Life-support-related medical equipment, etc.

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8.7 Soldering
(1) Soldering Condition
The recommended reflow soldering condition is shown in FIGURE 8.7.1.
High stress by mounting, such as long time thermal stress by preheating, mechanical stress, etc., can lead to degradation or destruction. Make sure that your mounting method does not cause problem as a system.
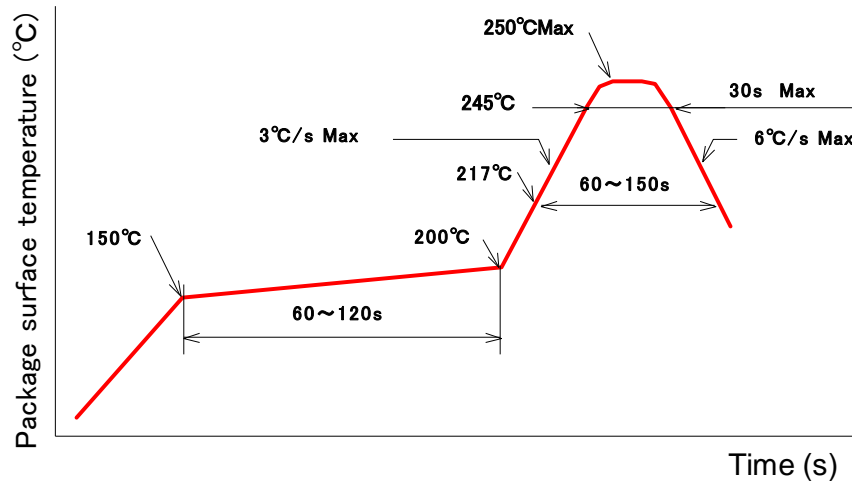
FIGURE 8.7.1 Recommended Conditions for Infrared Reflow or Air Reflow

(2) Reliability of Solder Connection
The reliability of solder connection depends on soldering condition, materials of circuit boards, footprint, etc. Test it sufficiently by heat cycle test, heat shock test, and so on after mounting ICs on circuit boards.

8.8 Storage Conditions
(1) Before opening the moisture prevention bag (aluminum laminate bag)
Temperature: less than 40°C
Humidity: less than 90%RH
Period: less than 12 months

(2) After opening the moisture prevention bag (aluminum laminate bag)
Temperature: 5°C to 30°C
Humidity: less than 60%RH
Period: less than 168 hours

※ When the period of (1) and (2) is likely to expire, store the IC in a drying furnace (10%RH or lower) at ordinary temperature.

(3) Baking process
When the period of (1) and (2) has expired, the IC should be baked in accordance with the following conditions. (However, when the IC is stored in a drying furnace (10%RH or lower) at ordinary temperature, there is no need to bake.) Do not bake the tape and the reel of the taping package because they are not heat resistant. Transfer the IC to a heat resistant container prior to baking.
Temperature: 125°C to 135°C
Period: more than 48 hours

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8.9 Others
   See "Instructions for Use of High-Voltage Monolithic ICs" and "Application Note" for other precautions and instructions on how to deal with these kinds of products.

9. Usage

(1) Our company warrants that our products have the specified performance according to the respective specifications at the time of its sale. Testing and other quality control techniques of our products by our company are utilized to the extent we need to meet the specifications described in this document. Not every device of our products is specifically tested on all parameters, except those mandated by relevant laws and/or regulations.

(2) Following any claim regarding the failure of a product to meet the performance described in this document made within one month of product delivery, all the products in relevant lot(s) shall be re-tested and re-delivered. Our products delivered more than one month before such a claim shall not be counted for such response.

(3) Our company assumes no obligation nor makes any promise of compensation for any fault which should be found in a customer's goods incorporating the products in the market. If a product failure occurs for reasons obviously attributable to our company and a claim is made within six months of product delivery, our company shall offer free replacement or payment of compensation. The maximum compensation shall be the amount paid for the products, and our company shall not assume responsibility for any other compensation.

(4) Our company reserves the right to make changes in this document and to discontinue mass production of the relevant products without notice. Customers are advised to confirm specification of the product of inquiry before purchasing of the products that the customer desired. Customers are further advised to confirm before purchasing of such above products that the product of inquiry is the latest version and that the relevant product is in mass production status if the purchasing of the products by the customer is suspended for one year or more.

(5) When you dispose of our products and/or packing materials, comply with the laws and regulations of each country and/or local government. Conduct careful preliminary studies about environmental laws applying to your products such as RoHS, REACH. Our company shall not assume responsibility for compensation due to contravention of laws and/or regulations.

(6) Our company shall not be held liable in any way for damages and infringement of patent rights, copyright or other intellectual property rights arising from or related to the use of the information, products, and circuits in this document.

(7) No license is granted by this document of any patents, copyright or other intellectual property rights of any third party or of our company.

(8) This document may not be reprinted, reproduced or duplicated, in any form, in whole or in part without the express written permission of our company.

(9) You shall not use our products (technologies) described in this document and any other products (technologies) manufactured or developed by using them (hereinafter called "END Products") or supply our products (technologies) and END Products for the purpose of disturbing international peace and safety, including (i) the design, development, production, stockpiling or any use of weapons of mass destruction such as nuclear, chemical or biological weapons or missiles, (ii) the other military activities, or (iii) any use supporting these activities. You shall not sell, export, dispose of, license, rent, transfer, disclose or otherwise provide our products (technologies) and END Products to any third party whether directly or indirectly with knowledge or reason to know that the third party or any other party will engage in the activities described above.
  When exporting, re-export transshipping or otherwise transferring our products (technologies) and END Products, all necessary procedures are to be taken in accordance with Foreign Exchange and Foreign Trade Act (Foreign Exchange Act) of Japan, Export Administration Regulations (EAR) of US, and any other applicable export control laws and regulations promulgated and administered by the governments of the countries asserting jurisdictions over the parties or transaction.

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◆Appendix - Supplementary Data

1. Dimensions
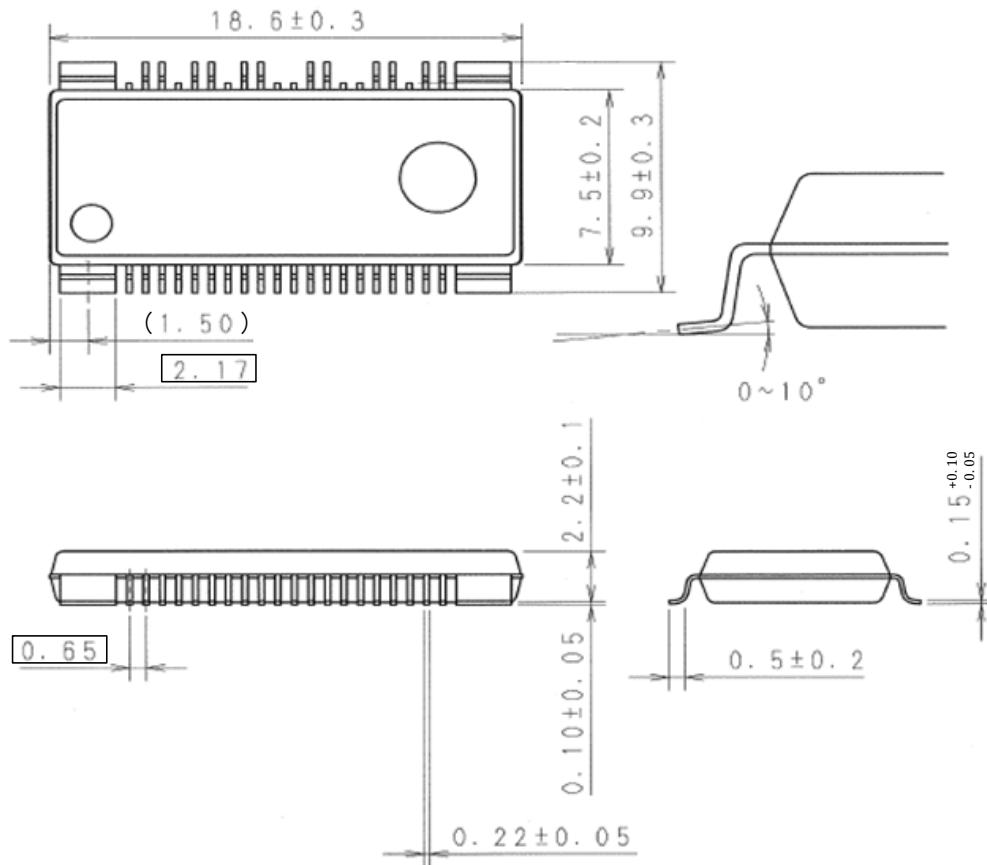
Unit: mm

FIGURE A: Dimensions

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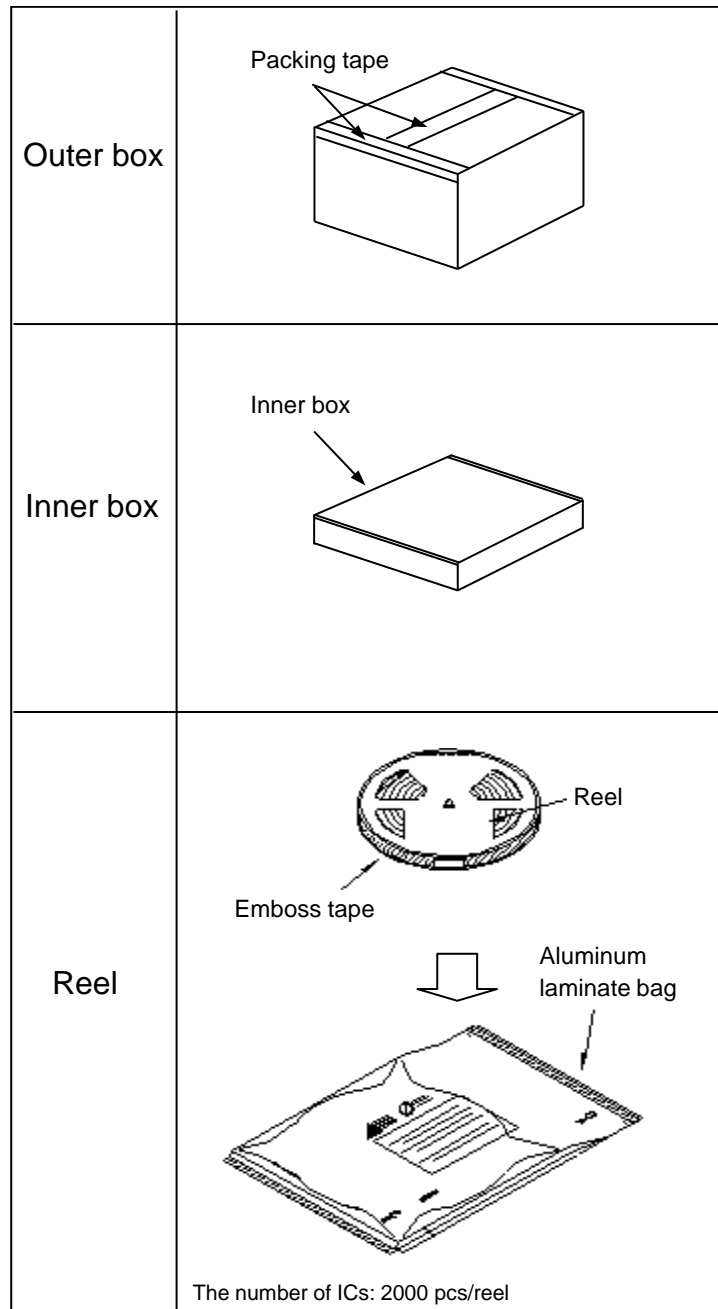
2. External Packaging
   FIGURE B shows the external packaging. Order quantities are basically multiples of 2000.

Outer box	Packing tape
Inner box	Inner box
Reel	Reel Emboss tape Aluminum laminate bag The number of ICs: 2000 pcs/reel

FIGURE B: External Packaging

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Precautions for Safe Use and Notices

If semiconductor devices are handled in an inappropriate manner, failures may result. For this reason, be sure to read the latest version of "Instructions for Use of High-Voltage Monolithic ICs" before use.

⚠ This mark indicates an item requiring caution.

⚠ **CAUTION** This mark indicates a potentially hazardous situation which, if not avoided, may result in minor or moderate injury and damage to property.

⚠ CAUTION

(1) Regardless of changes in external conditions during use of semiconductor devices, the "maximum ratings" and "safe operating area(SOA)" should never be exceeded when designing electronic circuits that employ semiconductor devices.

(2) Semiconductor devices may fail due to accidents or unexpected surge voltages. Accordingly, adopt safe design features, such as redundancy and measures to prevent misuse, in order to avoid extensive damage in the event of a failure.

(3) If semiconductor devices are applied to uses where high reliability is required, obtain the document of permission from MPSD in advance (Automobile, Train, Vessel, etc.). Do not apply semiconductor devices to uses where extremely high reliability is required (Nuclear power control system, Aerospace instrument, Life-support-related medical equipment, etc.).

(If a semiconductor device fails, there may be cases in which the semiconductor device, wiring or wiring pattern will emit smoke or cause a fire or in which the semiconductor device will burst.)

NOTICES

1. This Data Sheet contains the specifications, characteristics, etc. concerning power semiconductor products (hereinafter called "products").

2. All information included in this document such as product data, diagrams, charts, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, specifications of products, etc. are subject to change without prior notice. Before purchasing or using any of the MPSD products listed in this document, please confirm the latest product information with a MPSD sales office.

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When exporting, re-export transshipping or otherwise transferring the MPSD products (technologies) and END Products, all necessary procedures are to be taken in accordance with Foreign Exchange and Foreign Trade Act (Foreign Exchange Act) of Japan, Export Administration Regulations (EAR) of US, and any other applicable export control laws and regulations promulgated and administered by the governments of the countries asserting jurisdictions over the parties or transaction.

7. In no event shall MPSD be liable for any failure in MPSD products or any secondary damage resulting from use at a value exceeding the maximum ratings.

Refer to the following website for the latest information. Contact a MPSD sales office if you have any questions.

https://www.minebea-psd.com/en